

Photocoupler

KODENSHI

K4N25 • K4N25A

These Photocouplers consist of a Gallium Arsenide Infrared Emitting Diode and a Silicon NPN Phototransistor in a 6-pin package.

FEATURES

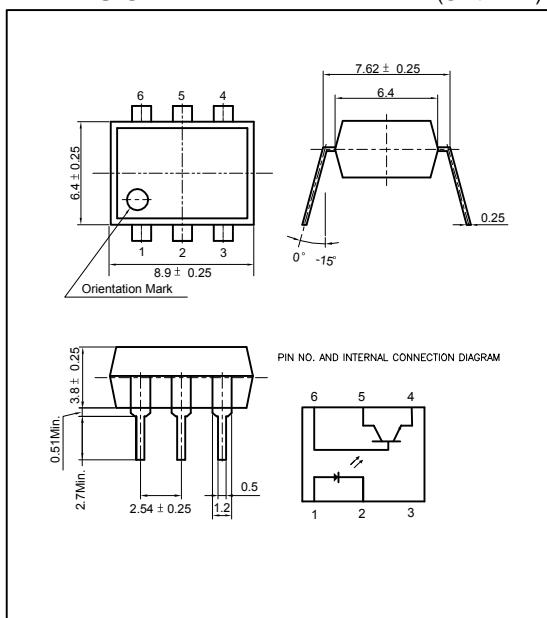
- Switching Time - Typ. 3 μ s
- Collector-Emitter Voltage : Min.30V
- Current Transfer Ratio : Typ.100% (at IF=10mA, VCE=10V)
- Electrical Isolation Voltage : AC2500Vrms
- UL Recognized File No. E107486

APPLICATIONS

- Interface between two circuits of different potential
- Vending Machine, Voltage Regulator
- Traffic Controller System
- Programmable Controller

DIMENSION

(Unit : mm)



MAXIMUM RATINGS

(Ta=25 °C)

Parameter	Symbol	Rating	Unit
Input	Forward Current	IF	80
	Reverse Voltage	VR	5
	Peak Forward Current *1	IFP	3
	Power Dissipation	Pd	70
Output	Collector-Emitter Breakdown Voltage	BVCEO	35 *4
	Emitter-Collector Breakdown Voltage	BVECO	6
	Collector-Base Breakdown Voltage	BVECO	70
	Collector Current	Ic	50
	Collector Power Dissipation	Pc	150
Input to Output Isolation Voltage *2	Viso	AC2500	Vrms
Storage Temperature	Tstg	-55~+125	
Operating Temperature	Topr	-30~+100	
Lead Soldering Temperature *3	Tsol	260	
Total Power Dissipation	Ptot	200	mW

*1. Input current with 100 μ s pulse width, 1% duty cycle

*2. Measured at RH=40~60% for 1min

*3. 1/16 inch form case for 10sec

*4. Customer Option

K4N25 • K4N25A**ELECTRO-OPTICAL CHARACTERISTICS**

(Ta=25°C , unless otherwise noted)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit.
Input	Forward Voltage	V _F	I _F =10mA	-	1.15	1.30	V
	Reverse Current	I _R	V _R =5V	-	-	10	μA
	Capacitance	C _T	V=0, f=1MHz	-	30	-	pF
Output	Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA	35	-	-	V
	Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E =0.1mA	6	-	-	V
	Collector-Base Breakdown Voltage	BV _{CBO}	I _C =0.1mA	70	-	-	V
	Collector Dark Current	I _{CEO}	I _F =0, V _{CE} =10V	-	-	100	nA
	Capacitance	C _{CE}	V _{CE} =0, f=1MHz	-	10	-	pF
Coupled	Current Transfer Ratio ^{*5}	CTR	I _F =10mA, V _{CE} =10V	20	-	-	%
	Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _F =50mA, I _C =1mA	-	0.15	0.4	V
	Input-Output Capacitance	C _{IO}	V=0, f=1MHz	-	1	-	pF
	Input-Output Isolation Resistance	R _{IO}	RH=40~60%, V=500V	-	10 ¹¹	-	Ω
	Rise Time	tr	V _{CE} =5V, R _L =100Ω I _C =2mA	-	3	-	μs
	Fall Time	tf		-	3	-	μs

*5. CTR=(I_C/I_F) X 100 (%)

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